

CEL&ETL – General Electronics

**T014**

Thursday, 29/11/2018

08:30 – 11:30 AM

WORKFORCE DEVELOPMENT AUTHORITY



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**ADVANCED LEVEL NATIONAL EXAMINATIONS, 2018,  
TECHNICAL AND PROFESSIONAL STUDIES**

**EXAM TITLE: GENERAL ELECTRONICS**

**OPTIONS: Computer Electronics (CEL)**

**Electronics and Telecommunication (ETL)**

**DURATION: 3 hours**

**INSTRUCTIONS:**

The paper is composed of **three (3) main Sections** as follows:

**Section I: Sixteen (16) compulsory questions. 55 marks**

**Section II: Attempt any three (3) out of five questions. 30 marks**

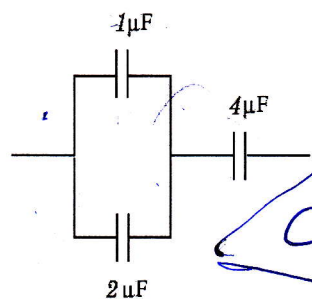
**Section III: Attempt any one (1) out of three questions. 15 marks**

**Note:**

***Every candidate is required to carefully comply with the above instructions. Penalty measures will be applied on their strict consideration.***

- 01. In most of electronic components ,semiconductors are preferable than conductors and insulators. Explain why? (3 marks)
- 02. When do you say that a pn junction diode is forward biased? (4 marks)
- 03. BJT are bipolar whereas UJT are unipolar.What does it mean? (4 marks)
- 04. a) Define Optoelectronics.  
b) What are the two main categories of optoelectronic devices? Give an example for each case. (6 marks)

05. Find the equivalent capacitance between point A and B of the following circuit:

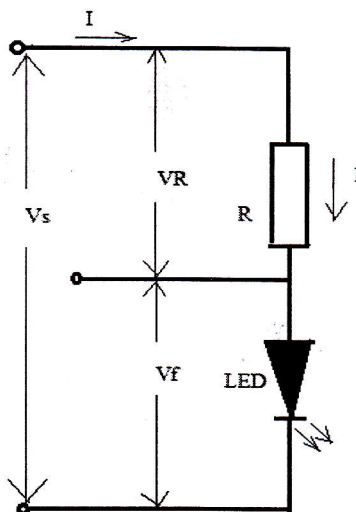


$\frac{1}{C_T} = \frac{1}{C_1} + \frac{1}{C_2} + \frac{1}{C_3}$  Parallel  
 $C_T = C_1 + C_2 + C_3$  Series

- 06. State two functions of an inductor in electronic circuits. (3 marks)
- 07. Which one is more doped between collector and emitter of NPN transistor? Explain your answer. (3 marks)

Emitter

08. Within an MP3 player design the indicator part is shown on the diagram below:



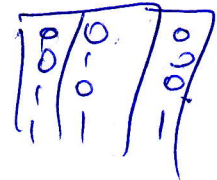
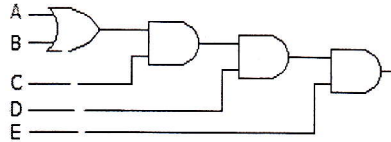
The datasheet of LED indicates that the limited current varies from 20mA to 100mA and the forward biased voltage is 1.8V. If the device will operate with a 3.7V battery, calculate the minimum and maximum value of the current limiting resistor R. (4 marks)

$I_F = 20 \times 10^{-3} A$   
 $I_C = 100 \times 10^{-3} A$   
 $V_F = 1.8 V$   
 $V_B = 3.7$

$\frac{V}{R} = \frac{V_F}{R} =$

$I_T = \frac{V_B}{V_F}$   $\left( \frac{R_2}{R_1 + R_2} \right) V_T$

09. Derive the Boolean expression for the logic circuit shown below:



(2 marks)

10. Draw the logic circuit using three NOR gates which outputs the following function:  $Y = AB$



(3 marks)

11. Give the range of the following resistor: Red Red Brown Silver . (4 marks)

12. a) Define a multimeter accuracy.

b) The datasheet of a multimeter shows that its accuracy is 1%. A technician has measured the voltage and found 220Volts. What is the actual voltage?

1

(4 marks)

13. What is the purpose of a filter circuit in common sens?

(3 marks)

14. What does express the ratio  $I_c/I_e$  or  $\alpha$  or the transport factor of a transistor?

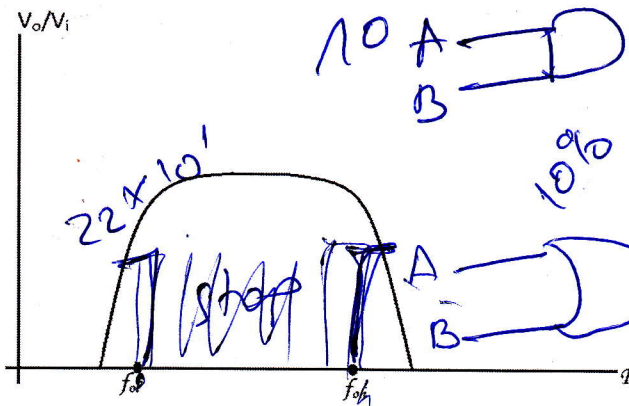
How is it affecting the quality of a transistor?

(3 marks)

15. How are photo-FETs activated?

(2 marks)

16. What type of filter does present the wave diagram below? Give one application of such a filter.



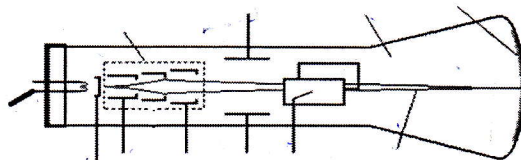
(4 marks)

**Section II. Choose and answer any three (3) questions.**

**30 marks**

17. Put the names (or label) of part of Cathode ray Oscilloscope as shown by short lines below:

(10 marks)



18. Simplify the following expression using Boolean algebra technique

$$Z = AB + A(B + C) + B(B + C)$$

(10 marks)

19. Explain the mode of operation of a potentiometer. (10 marks)

20. A transistor operating in CB configuration has  $I_C = 2.98 \text{ mA}$ ,  $I_E = 3.00 \text{ mA}$  and  $I_{CO} = 0.01 \text{ mA}$ . What current will flow in the collector circuit of this transistor when connected in CE configuration with a base current of  $30 \mu\text{A}$ ? (10 marks)

21. A. What are the important specifications of a digital-to-analog (D/A) converters do you base on during their selection?

B. Calculate the produced output voltage of a 10-bit digital-to-analog (D/A) converter having an output range from 0-9v when the input binary number is 1110001010. (10 marks)

$0.1 \times 10$

**Section III. Choose and answer any one (1) question.**

**15 marks**

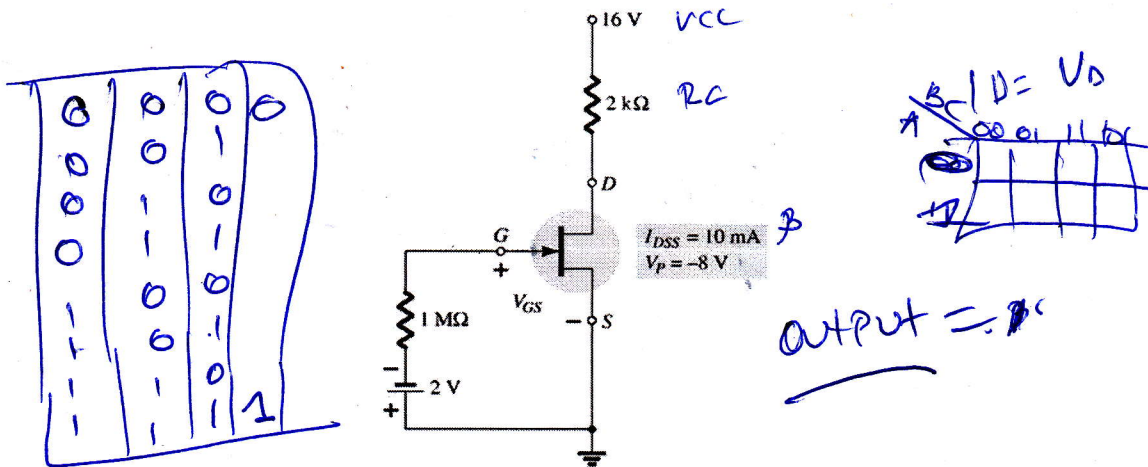
22. A crystal diode having internal resistance  $r_f = 20 \Omega$  is used for half-wave rectification. If the applied voltage  $v = 50 \sin \omega t$  and load resistance  $R_L = 800 \Omega$ , find: (i)  $I_m$ ,  $I_{dc}$ ,  $I_{rms}$

(ii) a.c. power input and d.c. power output

(iii) d.c. output voltage

(iv) Efficiency of rectification. (15 marks)

23. The circuit below is JFET fixed bias. Determine: (a)  $V_{GS}$ , (b)  $I_D$ , (c)  $V_{DS}$ , (d)  $V_D$ , (e)  $V_G$  and (f)  $V_S$ . (15 marks)



24. Design a 3-input (A,B,C) digital circuit that will give at its output (X) a logic 1 only if the binary number formed at the input has more ones than zeros.

a) Find the corresponding truth table,

b) Find output expression,

c) Simplify the output expression using K-map,

d) Draw the logic circuit. (15 marks)

A	B	C	X
0	0	0	0
0	0	1	0
0	1	0	0
0	1	1	1
1	0	0	0
1	0	1	1
1	1	0	1
1	1	1	1